NSN 5961-01-432-1005

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-432-1005 **Inclosure Material:** Metal **Overall Length:** 2.175 inches **Overall Width:** 0.075 inches **End Application:** E-3 esm prod grp b **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.0 breakdown voltage, dc **Power Rating Per Characteristic:** 2.0 watts small-signal output power, common-base pascal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Esd; junction pattern arrangement: pin **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0